**MICROSTRUCTURAL EFFECTS ON THE PHASE TRANSITIONS AND THE
THERMAL EVOLUTION OF ELASTIC AND PIEZOELECTRIC
PROPERTIES IN HIGHLY DENSE, SUBMICRON-STRUCTURED NaNbO_3
CERAMICS**

A. Moure^{*1}, T. Hungría², A. Castro², L. Pardo²

¹Instituto de Cerámica y Vidrio, CSIC, C/Kelsen, 5, 28049, Madrid, Spain

²Instituto de Ciencia de Materiales de Madrid, CSIC. Cantoblanco.
28049 Madrid, Spain.

ABSTRACT

The dielectric, piezoelectric and elastic coefficients, as well as the electromechanical coupling factors, of NaNbO_3 submicron-structured ceramics have been obtained by an automatic iterative method from impedance measurements at resonance. Poled thin disks were measured from room temperature up to the depoling one, close to 300°C. Dielectric thermal behaviour was determined also for unpoled ceramics up to the highest phase transition temperature. Ceramics were processed by hot-pressing from mechanically activated precursors. Microstructural effects on the properties are discussed. The suppression of the classical maximum in dielectric permittivity in unpoled ceramics at the phase transition at 370°C was found when a bimodal distribution of grain sizes, in which a population of average grain size of 110 nm in between much coarser grains is observed. The appearance of a phase transition at 150°C took place when Na vacancies are minimized. The occurrence of a non-centrosymmetric, ferroelectric phase, in the unpoled ceramic from room temperature to ~300°C, highly polarisable resulting in high ferro-piezoelectric properties was also

observed in the ceramic which presents grain size below 160 nm. Maximum values of $k_p=14\%$, $d_{31}=-8.7\cdot 10^{-12}$ C·N⁻¹ and $N_p=3772$ Hz·m at room temperature, and $k_p=18\%$, $d_{31}=-25.4\cdot 10^{-12}$ C·N⁻¹ and $N_p=3722$ Hz·m at 295°C were achieved in the best processing conditions of the ceramics.

Keywords: A. ceramic, D. Piezoelectricity, D. Microstructure.

INTRODUCTION

Alkaline niobates are considered good candidates to be an alternative for the substitution of commercial piezoceramics [1,2], which use highly toxic lead oxide in their processing. The solid solution with $K_{0.5}Na_{0.5}NbO_3$ composition is known to have piezoelectric properties at room temperature ($d_{33}\sim 80\cdot 10^{-12}$ C·N⁻¹) [3] that allows nowadays its commercial applications. Recently, it has been reported that d_{33} can be increased to $148\cdot 10^{-12}$ C·N⁻¹ in ceramics processed by spark plasma sintering [4]. The highest piezoelectric values by now for niobates based ceramics have been reported for textured $(K_{0.44}Na_{0.52}Li_{0.04})(Nb_{0.84}Ta_{0.10}Sb_{0.06})O_3$ compositions ($d_{33} = 416\cdot 10^{-12}$ C·N⁻¹) [5]. This result shows the potential of this family of compounds as lead-free piezoelectrics.

Within alkaline niobates, sodium niobate, $NaNbO_3$, is of particular interest because a number of solid solutions with good ferroelectric and piezoelectric properties [6-8] are based on this compound. It is antiferroelectric at room temperature [9], but the application of an electric field or the substitution of Na by Li [10] or K [11] induces a ferroelectric phase that provides piezoelectric activity, of interest mainly in high frequency devices. It presents a large number of polymorphic phases, variants of lower symmetry from the ideal perovskite structure. It undergoes six phase transitions [12]

* Corresponding author: Alberto Moure. alberto.moure@icv.csic.es.

from the non-polar high temperature phases (cubic $Pm3m$, tetragonal $P4/mbm$ and Orthorhombic $Cmmm$ and $Pnmm$) to the antiferroelectric room temperature phase (Orthorhombic $Pbcm$) and the low temperature ferroelectric one (Rhombohedral $R3c$).

As for every polar oxide ceramic, the functional properties, as piezoelectricity, of the alkaline-niobate ceramics depend on the grain size, a phenomenon commonly referred to as “size effect”. Its importance has increased during the last years within the nanotechnology field. Some of these effects are well-known in ferroelectric ceramics with perovskite-like structure, as the increase of the dielectric permittivity in $BaTiO_3$ down to a critical grain size [13,14]. However, there are still a lot of open questions about the size effects influence on the ferroelectric ceramics properties.

In the particular case of the $NaNbO_3$, it has been recently observed that the grain size reduction to submicron values produces a series of phase transformations due to the increasing internal pressures [15]. The appearance of a noncentrosymmetric structure in particle sizes below 400 nm improves the piezoelectric activity, as PFM studies of displacement against voltage show [16]. These phenomena can clearly influence the behavior with temperature of nano and submicron-structured $NaNbO_3$ ceramics [17], where several phase transitions occur. In this sense, some studies [18-20] were focused on the analysis of the transitions in the polar phase of ceramics with $Na_{1-x}Li_xNbO_3$ compositions, involving dielectric, thermal expansion and pyroelectric current measurements. However, although the phase transitions affect the thermal stability of their piezoelectric properties, not many works [21,22] study the evolution of the piezoelectric properties (electromechanical coupling factors or piezoelectric coefficient d_{ij}) with temperature.

It is known that the processing by classical methods of ceramics with alkaline niobate compositions in general, and $NaNbO_3$ in particular, shows difficulties in

obtaining densities near the theoretical [10,23]. This classical method involves high temperatures and long reaction times, produces the volatilisation of the alkali metal, leads to poor compositional homogeneity and provides products with large particles, and finally ceramics with the undesirable phenomena of exaggerated grain growth. The authors have recently carried out [24] a quantitative analysis of NaNbO_3 ceramics microstructures obtained from mechanical activation of different precursors. It was shown that highly dense ceramics (down to 0.4% of porosity) can be obtained at relatively low hot pressing temperatures (1000°C). This allows submicron-structured ceramics to be obtained with single grain size distributions with average grain size from 110 nm to 390 nm.

In this work, the thermal behaviour of the piezoelectric, elastic and dielectric properties of NaNbO_3 ceramics has been determined with the aim of study the microstructural effects on the functional properties of sodium niobate ceramics in the temperature range of piezoelectric activity. Ceramics studied were obtained by mechanical activation of several reagents and different hot-pressing conditions. It provides microstructures with different porosity and submicron grain size.

EXPERIMENTAL PROCEDURE

Ceramics with NaNbO_3 (NN) composition have been prepared from precursors obtained by mechanical activation from three different routes. The details of the precursor processing and its characterisation can be found elsewhere [25]. Ceramics disks of diameter (d) to thickness (t) ratio 1:10 were obtained by hot pressing at 200 MPa, 1000°C-2h (hereinafter called ceramics C-NN, DOH-NN-1 and O-NN-1, from Na_2CO_3 , NaOH and Na_2O precursors, respectively) and 1100°C-2h (hereinafter called ceramics DOH-NN-2 and O-NN-2) in a single thermal treatment from the mechanically

activated precursors. The microstructural study of the ceramics was previously carried out [24]. Hot pressing allowed highly dense (down to 0.4% for DOH-NN-1 ceramics) and mechanically stable submicron-structured ceramics to be obtained. The grain size was characterized as the equivalent diameter to a circular shape ($D_{eq} = 2(A/\pi)^{1/2}$), calculated from the measured grain area (A), which is a good approach since grains are equiaxed [24,26]. Average grain sizes (D_{equiv}) range from 110 to 390 nm. Intermediate sintering stages were observed for the O-NN-1 and DOH-NN-1 ceramics and bimodal lognormal grain size distributions were measured. Homogeneous microstructures with single lognormal distributions were obtained for the rest of the ceramics. Summarizing the previous study [24], all the microstructural parameters of interest for this work are given in Table I.

For the dielectric characterisation before poling, ceramics with 0.7-1.0 mm in thickness with Pt painted electrodes sintered at 900°C were prepared. Impedance measurements at 1 KHz and as a function of temperature were carried out with a HP4194A analyser, in an experimental set-up for the temperature control described in [27]. The heating and cooling rates were 2°C/min. From these experimental data and a geometry factor thickness/area, complex dielectric permittivity, $\epsilon^* = \epsilon' - i\epsilon''$, and dielectric losses, $\tan \delta = \epsilon''/\epsilon'$, were obtained.

After the dielectric measurements, the ceramics were poled up to saturation in a silicon oil bath at 120-180°C with electric fields as high as 6000 kV/m. Dielectric (ϵ_{33}^T at the resonance frequency), elastic (s_{11}^E and s_{12}^E), and piezoelectric coefficients (d_{31}), including all losses, as well as electromechanical coupling factors (k_p) and frequency numbers (N_p) corresponding to the radial resonance mode of thin disk shaped ceramics at room temperature were measured by the automatic iterative method of Alemany et al., described elsewhere [28]. Measurements were also carried out as a function of

temperature with a procedure also explained elsewhere [29] using a HP4192A impedance analyzer.

RESULTS

Figures 1 and 2 show the evolution with temperature of the dielectric permittivity, ϵ' , and loss factor, $\tan \delta$, at 1 KHz for unpoled NN ceramics. A sharp dielectric anomaly on heating with strong thermal hysteresis ($\sim 50^\circ\text{C}$) is observed at $\sim 370^\circ\text{C}$ for DOH-NN-2 and at 355°C for C-NN ceramics. This is currently ascribed in the literature first order phase transition from the to the antiferroelectric RT phase [12,18]. A maximum of ϵ' at the phase transition (T_C on heating) is not well defined for the O-NN-1 ceramics. The O-NN-2 ceramics phase transition can be observed but with a strong diffuse character in contrast with the first order phase transition shown by the rest of the ceramics. There is a displacement of T_C on heating with respect to the reported one for NaNbO_3 single crystals and coarse grained ceramics ($T_C \sim 370^\circ\text{C}$) [12,18], severe for the DOH-NN-1 ($T_C \sim 306^\circ\text{C}$) and moderate for the C-NN ceramics ($T_C \sim 355^\circ\text{C}$). The insets in Figures 1 represent the details of the temperature dependence of the dielectric permittivity up to 250°C . An anomaly at $\sim 150^\circ\text{C}$ is observed for the C-NN ceramics. The O-NN-1 ceramics has the largest values of dielectric losses. For the O-NN-1 ceramics, a tail close to room temperature is observed. It is probably related with conduction phenomena, and is out of the scope of this work.

Figure 3 shows the peaks of the real part of the complex impedance ($R = \text{a.c. resistance}$) and the real part of the complex admittance ($G = \text{a.c. conductance}$) at the planar resonance modes of the poled ceramic disks and their reproduction from the calculated parameters by the iterative method at resonance for all the NaNbO_3 hot pressed ceramics, except for the O-NN-1 ones. The spectra are represented at room

temperature (RT) and at 310°C only for the ceramics for which the resonances are clearly distinguished (C-NN and DOH-NN-2) at that temperature.

Dielectric, elastic and piezoelectric coefficients, as well as the electromechanical coupling factors and frequency numbers, calculated from the resonance spectra at room temperature (Figure 3) are shown in Table I. The peaks are wider for the C-NN ceramics, as it corresponds to lower values of the mechanical quality factors $Q_m (s_{11}^E)$ and $Q_m (s_{12}^E)$ shown in Table I. The highest piezoelectric activity (highest k_p and d_{31} values) corresponds to the C-NN ceramic, while the elastic parameters (N_p , s_{11}^E , s_{12}^E) show that DOH-NN-2 is the stiffest ceramic and DOH-NN-1 the most compliant.

Figure 4(a) shows the evolution with temperature of the real part of the planar electromechanical coupling factor (k_p) of NaNbO₃ ceramics. Except for O-NN-2, which has a softer decrease over a wider temperature range, all of them present the same shape, with a variation from room temperature up to ~300°C and a sharp decrease from that temperature. At ~300°C, k_p abruptly decreases but there is still a measurable electromechanical resonance for C-NN and DOH-NN-2. At ~325°C none of the ceramics presents piezoelectric activity. This is also a lower temperature than the one of the phase transition from the antiferroelectric phase measured on heating for the unpoled ceramics (Figure 1). The highest values in all the temperature range under study correspond to the C-NN ceramic, while the O-NN-2 one presents the lowest ones. The curve for the O-NN-1 ceramic has not been measured. The reason is that this ceramic presents a high conductivity and is very difficult to pole. Ultra-fine intergranular porosity accompanying the family of smaller grain sizes of its bimodal grain size distribution was observed in this ceramic. Porosity is detrimental for the grain connectivity needed for the establishing of a homogeneous electric field in the ceramic. The achieved piezoelectric activity is very low ($d_{33}=6\cdot 10^{-12}$ C·N⁻¹), and the ceramic is

rejected for further measurements as a function of the temperature as it lacks a practical interest.

Figure 4(b) shows the evolution with temperature of the real part of the piezoelectric coefficient d_{31} . It has the same dependence with processing conditions and measuring temperatures as k_p , but the increase from room temperature up to $\sim 300^\circ\text{C}$ is remarkable for C-NN and DOH-NN-1 ceramics and almost multiply by 3 the value at 50°C . The highest values also correspond to the C-NN ceramic. It has its maximum at 295°C , where $d_{31} = -25.4 \cdot 10^{-12} \text{ C} \cdot \text{N}^{-1}$.

Figure 5(a) shows the dependence with temperature of the planar frequency number N_p . In all the curves, there is a decrease in N_p , meaning a softening of the ceramic, up to the temperatures where piezoelectric activity tends to zero (Figures 4a and 4b). Then, N_p rapidly increases. This increase occurs also over a wider temperature interval (from $\sim 250^\circ\text{C}$) for the O-NN-2 ceramic than for the rest. The DOH-NN-2 ceramic has the highest values in all the temperature range, while the DOH-NN-1 one has the lowest ones.

The measurement of the resonance frequency, and thus of $N_p = f_s^p \cdot d$, is much more accurate than the calculation of any of the obtained parameters from the resonance spectrum. Despite of this, the evolution with temperature of the elastic compliances s_{11}^E and s_{12}^E , shown in Figures 5b and 5c, shows also the main facts described for the thermal evolution of N_p . The highest values correspond to the DOH-NN-1 ceramic, and the lowest ones to the DOH-NN-2 one. A jump in the s_{11}^E and s_{12}^E coefficients at 150°C is observed only for the C-NN ceramic.

DISCUSSION

The processing of the ceramics from three different types of powders and two hot-pressing temperatures gave place to variations of the microstructural factors that define the ferro-piezoelectric performances found in each ceramic. A certain number of the observed characteristics cannot be easily understood as classical grain size and porosity dependences. The explanation of all these characteristics needs analysis of other ceramic microstructural features.

This is the case of the lack of a well defined maximum in T_C on heating or cooling, together with the lowest values in the curve of the unpoled dielectric permittivity, for O-NN-1 ceramics. These are accompanied by the small piezoelectric activity of the O-NN-1 ceramic ($d_{33}=6\cdot 10^{-12} \text{ C}\cdot\text{N}^{-1}$). To understand it we have to take in consideration, recently published, new information on the structure of NaNbO_3 powder nanoparticles. Raman spectroscopy studies on NaNbO_3 powder samples have shown a diffuse phase transition [30] at 180°C , with no other changes taking place at higher temperatures, in particles with sizes $<70 \text{ nm}$. At increasing grain size to the submicron range (200-400 nm) a noncentrosymmetric structure at room temperature is developed with a phase transition taking place in a temperature interval from 310 to 330°C [15]. For particle sizes $>1 \text{ }\mu\text{m}$, the phase transition is observed at 370°C , corresponding to the commonly measured antiferro-paraelectric phase transition for single crystals and unpoled ceramics with grain size in the micron range [18]. The reduced ceramic grain size of the O-NN-1 sample seems to inhibit the polarizability of the lower size population, suppressing the antiferroelectric phase before poling and the phase transition from this, as observed by the lack of anomalies above 180°C in the Raman spectra of particles below 70 nm . The microstructure of the O-NN-1 can be described as antiferroelectric isolated regions with high dielectric permittivity surrounded by a nano

grain size generated non-polar phase, and thus with low dielectric permittivity, regions that present an overall low dielectric permittivity and polarizability, due to lack of continuity between electrodes of the former. This effect is the well-known one for the piezoelectric composites consisting of isolated ferroelectric particles of high permittivity dispersed in a low permittivity polymer (0-3 connectivity composites) [31].

The strong T_C reduction on heating for unpoled DOH-NN-1 ceramic is accompanied by one of the best piezoelectric properties. It is remarkable that the shift to lower temperatures of T_C on heating in the transition from the phase at room temperature for the unpoled ceramics (up to 64°C reduction for DOH-NN-1 with respect to DOH-NN-2) revealed by the dielectric permittivity vs. temperature measurements (Figure 1) does not have influence on the temperature range of ferro-piezoelectric activity of the ceramics after poling (Figures 4 and 5). All the ceramics, including the DOH-NN-1 one, keep ferro-piezoelectric activity up to ~295°C. This depoling temperature and the shape of the curve are similar to the reported in [21, 22] for NaNbO_3 and Li doped NaNbO_3 with low Li contents. It is directly related with the temperature evolution of the remnant ferroelectric polarization in NaNbO_3 poled ceramics [32]. Therefore, the transition from the ferroelectric phase that was induced by poling to a non-piezoelectric, centrosymmetric, one seems to take place near 300°C for all ceramics.

The DOH-NN-1 ceramic presents a bimodal grain size distribution in the limit between submicron- and nano-structure. One of the populations of this bimodal distribution is built-up by well formed grains with an average grain size of 160 nm. The second population consists of clusters, with an internal structure of grains in coalescence with an average grain size well below 100 nm [24] (Figure 6a). Such microstructure seems to be in the origin of the distinct permittivity vs. temperature

curve with a T_C on heating at $\sim 300^\circ\text{C}$. Figures 6a and 6b depict the dielectric permittivity values before (ϵ' at $3 \cdot 10^5$ Hz) and after poling (ϵ_{33}^T at the planar resonance in the same frequency range as the ϵ' plot (Figure 3)) of the DOH-NN-1 and 2 ceramics, respectively. Whereas for the DOH-NN-2 there is a strong difference between the shapes of the two curves, as it corresponds to the fact that they are measurements of two distinct phase transitions taking place at different temperatures. While the curve for the unpoled sample measures a phase transition from the antiferroelectric phase, the curve for the poled one measures a transition from the ferroelectric induced by poling. Contrarily, the shape of the curves for DOH-NN-1 is identical, suggesting that both measurements corresponds to the same phase transition. That is to say, the same phase transition takes place for both the unpoled and poled samples. Poled samples present below the transition a field induced ferroelectric phase. This means that in the unpoled state of the DOH-NN-1 ceramic the very fine and dense microstructure stabilizes a ferroelectric phase, in the absence of the electric field and below the transition temperature (300°C), instead of the antiferroelectric one. The parallel behaviour of the thermal evolution for unpoled and poled DOH-NN-1 ceramics shows that the unpoled ceramic has, similarly to what was found by Raman study for submicron particles from room temperature to $\sim 300^\circ\text{C}$ [15], a highly polarizable non-centrosymmetric phase, stabilized by the very fine and dense microstructure.

Such phenomenon is not unique. On the contrary, in artificially layered ferroelectric-dielectric superlattices, the electrostatic coupling between alternating thin ferroelectric and dielectric layers is able to induce a polarization in the latter and, when the dielectric is sufficiently polarizable, this yields an uniformly and highly polarizable phase and the appearance of high dielectric permittivity values and tuning of the phase transition temperature [33]. Similar electrostatic coupling could take place in between

nanoregions of antiferroelectric, polarizable phase, and those of ferroelectric one. Such nanoregions, as observed in NaNbO_3 single crystals, would be due to local differences in Na vacancies content [34]. The coupling would be favored by the high density and very fine grain of the DOH-NN-1 ceramics.

The high temperature phase after the transition at $\sim 300^\circ\text{C}$ for the DOH-NN-1 ceramic must be different than for the rest of the ceramics. For these, the antiferroelectric (polar and non-piezoelectric) room temperature phase must take place after depolarization and up to the transition at 370°C (Figure 1). The absence for DOH-NN-1 unpoled ceramics of other dielectric anomalies above the depolarization temperature (Figure 1), suggests that the transition at 306°C takes place to another phase. This will also explain the different a.c. conductivity at resonance and subsequent difficulties in the material parameters calculation after the phase transition in the DOH-NN-1 ceramics.

The anomaly in dielectric permittivity at $\sim 150^\circ\text{C}$ in both heating and cooling runs, clearly observed in the insets of the Figure 1 only for the C-NN ceramics, shows a second order phase transition previously reported in NaNbO_3 single crystals [35]. It has also been observed in Raman spectroscopy studies in NaNbO_3 powder [36], in both heating and cooling runs, and in spark plasma sintered ceramics [32]. The anomaly is also observed here as a jump in the elastic compliance coefficients s_{11}^E and s_{12}^E (Figures 5b and 5c). In this case, the measurement is performed after poling, when a ferroelectric phase is induced by the application of an electric field [32]. It can be concluded that the phase transition at $\sim 150^\circ\text{C}$ is produced inside ferroelectric regions induced, which most likely exist also in unpoled ceramics. It has been reported in unpoled single crystals of NaNbO_3 the existence at room temperature of a ferroelectric phase (called as M), with a different structure than the ferroelectric phase (called Q) resulting from the application

of an electric field. The observed phase transition occurs between the M and the Q phase. In the same work [34], it is also proposed that in regions where Na composition is lower than the stoichiometric one, and many Na vacancies exist, the occurrence of an antiferroelectric structure (P) is favoured. When DOH-NN or O-NN precursors are used, Na-sites defects can increase, by evaporation. It would favour the P antiferroelectric phase [34] and inhibits the forming of M phases. This explains why, in those cases, phase transition at $\sim 150^{\circ}\text{C}$ is not observed. It is also possible that the long milling time for the precursors of the C-NN ceramics (30 days [25]) could result in a better mixing of the powder as well as the incipient mechanosynthesis, which reduces the stoichiometric faults. The existence of these regions of ferroelectric phase in the unpoled state is responsible of the C-NN ceramics piezoelectric coefficients to be the highest ones among the obtained in all the ceramics of this work (Table I).

The shape of the temperature dependence of the elastic properties (N_p , s_{11}^E , s_{12}^E) is in good agreement with the increase in Young's modulus reported in sodium niobate ceramics with 1% Li content [19]. The differences among the ceramics (Figure 5) seem to indicate a double influence of the microstructure due to porosity and the homogeneity in grain size of the ceramics. The C-NN and O-NN-2 ceramics have a similar grain size (220 and 240 nm, respectively), but N_p (Figure 5a) is higher for the latter due to their lower porosity (3.8 compared with 6.4% of porosity, see Table I). Besides a comparatively higher vacancies content in O-NN-2 (higher processing temperature favours Na evaporation) produces an electromechanical stiffening due to domain wall trapping by vacancies [29], that also reduces the extrinsic component of the domain walls to the piezoelectric activity, reducing the d_{31} coefficient and coupling factor (Figure 4). The trend with porosity content is the opposite if the DOH-NN-1 (0.4%) and DOH-NN-2 (2.1%) ceramics are compared. As Figure 6 shows, the former ceramic has

a bimodal grain size distribution that contains clusters, with an internal structure of grains in coalescence. The increase of the hot pressing temperature to 1100°C gives place to a single grain size distribution in DOH-NN-2. The clusters in DOH-NN-1 must be softer, and it together with the relatively lower content of vacancies of these ceramics make them the most compliant.

CONCLUSIONS

Microstructural effects on the dielectric, piezoelectric and elastic properties of dense submicron structured NaNbO_3 ceramics, were studied up to the same or higher temperatures than the depoling ones.

For dense ceramics with similar submicron average grain size and that show single grain size distributions, the unpoled dielectric permittivity as a function of temperature presents the usual facts measured for NN single crystals and coarse-grain ceramics. The differences of the coefficients obtained from the electromechanical resonance, the phase transition at 150°C for C-NN, the strong dielectric permittivity decrease and dielectric losses increase for O-NN-2, can be interpreted in terms of the differences in the composition (secondary phases).

For dense ceramics with a bimodal grain size distribution that contain a great extend of a submicron grains population, with ultrafine intergranular porosity in between grains of microns size, an inhibition of the antiferroelectric phase in the finer grain population is observed, suppressing the maximum of the dielectric permittivity with temperature. The non-polar phase surrounding the antiferroelectric grains causes a reduction of dielectric permittivity and polarizability, 0-3 connectivity type composite effect, in the O-NN1 ceramic that greatly reduces the ferro-piezoelectric activity after poling.

The second of the grain size effects, not yet reported in the literature for ceramics, was found in the ceramic with the highest density having also a bimodal grain size distribution. The unpoled ceramic has a microstructure stabilized non-centrosymmetric ferroelectric phase. It is a highly polarizable phase which contributes to the enhancement of the dielectric and piezoelectric properties.

Summarizing, these results show the microstructural factors that affect the phase transitions and piezoelectric performance of highly dense, submicron structured NaNbO_3 ceramics and improve the coupling factors (up to $k_p \sim 12\text{-}14\%$) and mechanical quality factors (up to $Q_m (s_{11}^E) > 800$). This knowledge has practical interest in the obtention of high performance lead-free piezoelectric solid solution systems containing NaNbO_3 .

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FIGURE CAPTIONS

Figure 1. Real part of the dielectric permittivity at 1000 Hz as a function of temperature for NaNbO₃ hot pressed ceramics (solid symbols: heating; open symbols: cooling). Inset: Magnifications of Figure 1 from 50 to 250°C

Figure 2. Dielectric losses at 1 kHz as a function of temperature for NaNbO₃ hot pressed ceramics (solid symbols: heating; open symbols: cooling).

Figure 3. R and G curves at room temperature (RT) and at 310°C of resonance (closed squares) and antirresonance (open circles) and reproduction from the constants obtained by the iterative method (line) at planar resonance of NaNbO₃ hot pressed ceramics.

Figure 4. Thermal evolution of the: (a) Planar electromechanical factor k_p and (b) Real part of the piezoelectric coefficient d_{31} for NaNbO₃ hot pressed ceramics.

Figure 5. Thermal evolution of the: (a) planar frequency number N_p ; (b) compliance coefficient s_{11}^E and (c) compliance coefficient s_{12}^E for NaNbO₃ hot pressed ceramics.

Figure 6. Real part of the dielectric permittivity as a function of temperature for poled and unpoled (a) DOH-NN-1 ceramics and (b) DOH-NN-2 ceramics (solid symbols: unpoled ceramics, measured at $3.6 \cdot 10^5$ Hz; open symbols: poled ceramics, measured at resonance frequencies). Inset: SEM micrographs of polished and thermally etched surfaces of the corresponding ceramics.

TABLE CAPTIONS

Table I. Piezoelectric, elastic and dielectric characterisation at room temperature of the planar resonance of thin disks of NaNbO₃ hot pressed ceramics. Microstructural factors (percentage of porosity and mean value ($\langle D_{\text{equiv}} \rangle$) and standard deviation ($\sigma_{D_{\text{eq}}}$) of the grain size distributions) reported in ref [24] are also shown (measurement error for grain size: $\pm 20\text{nm}$; *: bimodal grain size distribution, value shown corresponding to the largest grain size).

Figure 1

Figure 2

Figure 3

Figure 4

Figure 5

Figure 6

Table I

NaNbO ₃ ceramics	C-NN 1000°C	O-NN-2 1100°C	DOH-NN-1 1000°C	DOH-NN-2 1100°C
Porosity (%)	6.4±0.8	3.8±0.3	0.40±0.02	2.10±0.06
< D _{eq} > (nm)	220	240	160*	390
σ _{Deq} (nm)	120	120	80	230
T _C ^{heating} (°C)	355	371	307	371
d ₃₃ (10 ⁻¹² C·N ⁻¹)	40	24	38	32
k _p (%)	14	8	12	12
d ₃₁ (10 ⁻¹² C·N ⁻¹)	-8.7+0.09i	-5.2+0.12i	-7.8 + 0.06i	-7.2+0.03i
N _p (Hz·m)	3571	3535	3252	3778
s ₁₁ ^E (10 ⁻¹² m ² ·N ⁻¹)	8.5-0.04i	7.8-0.01i	9.7 - 0.03i	6.7-0.008i
Q _m (s ₁₁ ^E)	200	660	344	863
s ₁₂ ^E (10 ⁻¹² m ² ·N ⁻¹)	-1.4+0.0065i	-1.9+0.0031i	-2.2+0.0211i	-1.6+0.0018i
Q _m (s ₁₂ ^E)	217	606	106	859
ε ₃₃ ^T	144+1.77i	154+1.44i	133 + 1.64i	158+1.79i